NSN 5962-01-050-6933

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-050-6933
Body Length:
Between 0.750 inches and 0.795 inches
Body Width:
Between 0.245 inches and 0.300 inches
Body Height:
Between 0.120 inches and 0.195 inches
Maximum Power Dissipation Rating:
657.0 milliwatts
Operating Tempurature Range:
+0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and w/enable and high speed and programmable and programmed and schottky and w/open collector
and bipolar and w/buffered output and w/decoded output and expandable and w/disable and positive outputs
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Case Outline Source And Designator:
-0-001-ag joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
75.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Prom
Memory Capacity:
Unknown
Test Data Document:
94117-7013655 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)

N/a

Unit Of Measure:

16 printed circuit

Shelf Life:

Terminal Type And Quantity:

NSN 5962-01-050-6933

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

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